OIPE IAP81 JAN 05 2009 PATENT & TRADEMARK OFFICE

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Applicant:		§	
		§	
Arkadiy MORGENSHTEIN et al		§	
		§	
Serial No.: 10/825,123		§	
		§	
Filed:	April 16, 2004	§	Group Art Unit: 4128
		§	
For:	ION CONCENTRATION TRANSISTOR AND DUAL-MODE SENSORS (amended)	§	
		§	
		§	Attorney Docket: **27238**
Examiner:	John C. BALL	§	

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

DECLARATION UNDER 37 CFR 1.131

Sir:

I, Yael NEMIROVSKY of 7 Golda Street, Haifa, Israel, declare as follows:

1. I am a joint inventor of the invention disclosed and claimed in the above-identified application;

2. I supervised the Research Thesis titled "Design an Methodology of ISFET (Ion Sensitive Field Effect Transistor) Microsystems for Bio-Telemetry" authored and submitted by Arkady Morgenshtein. Arkady Morgenshtein, Prof. Uri Dinnar and me jointly contributed to the inventive concepts presented in the Thesis. Arkidy Morgenshtein is named as an author of the Thesis as is customary for Master students in their Research Thesis; and

3. I declare that all statements made herein of our knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements are made with the knowledge that willfully false statements are punishable by fine or imprisonment under 18 U.S.C. Section 1001 and that any such statement may jeopardize the validity of the subject application or any patent issued thereon.

Yael Nemirovsky
Yael NEMIROVSKY

December 30, 2008
Date